

K. J. SANKARAN

Postdoctoral Research Fellow,
Institute for Materials Research,
Hasselt University,
Campus Diepenbeek, Wetenschapspark 1
Diepenbeek 3590, Belgium.

Email: jothisankaran@gmail.com, Mobile number: +91-6369322495



EDUCATION

Ph.D, Materials Science and Engineering, National Tsing Hua University, Taiwan (2013).
M.Sc, Materials Science (Ist Division), College of Engineering, Anna University, India (2007).
B.Sc, Physics (Ist Division, Rank Holder), Madurai Kamaraj University, India (2005).
Higher Secondary (Ist Division), Devangar Higher Secondary School, Tamilnadu, India (2002).
Secondary (Ist Division), Devangar Higher Secondary School, Tamilnadu, India (2000).

AWARDS/SCHOLARSHIPS

- ✧ FWO Postdoctoral Research Fellowship, Belgium (2015–2018).
- ✧ FWO Pegasus Marie Curie Postdoctoral Research Fellowship, Belgium (2014–2015).
- ✧ Postdoctoral Research, National Science Council, Taiwan (2013–2014).
- ✧ National Tsing Hua University Outstanding Student Scholarship (2010–2013).
- ✧ Best Poster Presentation Award: AVS-IPW 2011, Taiwan.
- ✧ Best Poster Presentation Award: TACT Student's Symposium 2013, Taiwan.
- ✧ Best Oral Presentation Award: TACT Student's Symposium 2014, Taiwan.
- ✧ Best Poster Presentation Award: 7th International Symposium on Surface Science 2014, Japan.
- ✧ Best Poster Presentation Award: 13th New Diamond and Nano Carbons Conference 2019, Taiwan

RESEARCH INTERESTS

- Synthesis of low temperature grown diamond films on printed polymer substrates for flexible electronics.
- Diamond-Gallium nitride heterostructures for high power electronics.
- Synthesis of diamond films using graphene nucleation.
- Synthesis of hybrid diamond films (with CNT or graphene) for potential applications.
- Will to explore my knowledge and experience in synthesizing carbon related hybrid

materials and characterize the materials using transmission electron microscopy.

RELEVANT EXPERIENCE

- ✧ **Ph.D research**, Dept. of Materials Science and Engineering, National Tsing Hua University (2009–2013): “*Investigations of the Structural and Electron Field Emission Properties of Ultrananocrystalline Diamond Films (UNCD)*”.
- ✧ **Senior Postdoctoral Researcher**, Hasselt University, Hasselt, Belgium (2018–2019): “*Low temperature grown nanocrystalline diamond films for potential applications*” sponsored by Hasselt University, Belgium.
- ✧ **FWO Postdoctoral Research Fellow**, Hasselt University, Hasselt, Belgium (2015–2018): “*Nanocrystalline Diamond-based Hybrid Thermionic Electron Emitters*” sponsored by FWO, Belgium.
- ✧ **FWO Research Grant**, Hasselt University, Hasselt, Belgium (2016–2017): “*Electrically conductive nanocrystalline diamond for microplasma cathode application*” sponsored by FWO, Belgium (40000 Euros).
- ✧ **FWO Pegasus Marie Curie Postdoctoral Research Fellow**, Hasselt University, Hasselt, Belgium (2014–2015): “*Field Enhanced Thermionic Electron Emission from Surface Treated n-type doped Nanocrystalline Diamond Nanostructures*” sponsored by FWO, Belgium.
- ✧ **Postdoctoral Research Fellow**, National Tsing Hua University, Hsinchu, Taiwan (2013–2014): “*Microstructural evolution of diamond films from plasma energetic species and their enhanced electrical properties*” sponsored by National Science Council, Taiwan.
- ✧ **Research Assistant**, Central Electrochemical Research Institute (CECRI), Karaikudi, India (2007–2009): “*Galvanic corrosion performance of Magnesium alloys in automotive applications*” sponsored by General Motors, USA.
- ✧ **M.Sc Thesis**, Dept. of Physics, College of Engineering, Anna University, Chennai, India (2007): “*Growth and Characterization of Boric acid doped Potassium dihydrogen phosphate crystals for non-linear optics applications*”.
- ✧ **M.Sc Summer Internship**, S N Bose National Centre for Basic Sciences, Kolkata, India (2006): “*The applicability of rigid band model to describe doping in realistic systems*”.

PUBLICATIONS IN INTERNATIONAL JOURNALS

Book chapter

Kamatchi Jothiramalingam Sankaran and Ken Haenen, “Nitrogen Incorporated (Ultra)Nanocrystalline Diamond Films for Field Electron Emission Applications” in [Novel Aspects of Diamond \(2nd Edition\)](#), Springer 2019, pp 123-171.

Refereed Journals

1. K. J. Sankaran, P. T. Joseph, N. H. Tai, and I. N. Lin, “High dose N ion implantation effects on surface treated UNCD films,” [Diamond and Related Materials](#), 19, 927 (2010) (Peer reviewed).
Impact Factor: [1.825](#).
2. Y. C. Lin, K. J. Sankaran, Y. C. Chen, C. Y. Lee, H. C. Chen, I. N. Lin, N. H. Tai, “Enhancing electron field emission properties of UNCD films through nitrogen incorporation at high substrate temperature,” [Diamond and Related Materials](#), 20, 191 (2011) (Peer reviewed).
Impact Factor: [1.913](#).
3. K. J. Sankaran, P. T. Joseph, H. C. Chen, N. H. Tai, and I. N. Lin, “Investigation in the role of hydrogen on the properties of diamond films grown using Ar/H₂/CH₄ microwave plasma,” [Diamond and Related Materials](#), 20, 232 (2011) (Peer reviewed).
Impact Factor: [1.913](#).
4. K. Y. Teng, H. C. Chen, H. Y. Chiang, C. C. Horng, H. F. Cheng, K. J. Sankaran, N. H. Tai, C. Y. Lee, I. N. Lin, “The role of nano-graphite phase on the enhancement of electron field emission properties of ultrananocrystalline diamond films,” [Diamond and Related Materials](#), 24, 126 (2012) (Peer reviewed).
Impact Factor: [1.913](#).
5. Kamatchi Jothiramalingam Sankaran, Kalpataru Panda, Balakrishnan Sundaravel, Huang-Chin Chen, I-Nan Lin, Chi-Young Lee, and Nyan-Hwa Tai, “Engineering the Interface Characteristics of Ultrananocrystalline Diamond Films Grown on Au-Coated Si Substrates,” [ACS Applied Materials Interfaces](#), 4, 4169 (2012) (Peer reviewed).
Impact Factor: [4.525](#).
6. Kalpataru Panda, N. Kumar, K. J. Sankaran, B. K. Panigrahi, S. Dash, H. C. Chen, I. Nan Lin, N. H. Tai, A.K. Tyagi, “Tribological properties of ultrananocrystalline diamond and diamond nanorod films,” [Surface and Coatings Technology](#), 207, 535, (2012) (Peer reviewed).
Impact Factor: [1.867](#).
7. K. J. Sankaran, J Kurian, H C Chen, C L Dong, C Y Lee, N H Tai and I N Lin, “Origin of a needle-like granular structure for ultrananocrystalline diamond films grown in a N₂/CH₄ plasma,” [Journal of Physics D: Applied Physics](#), 45, 365303 (2012) (Peer reviewed).

Impact Factor: [2.544](#).

8. Kamatchi Jothiramalingam Sankaran, Srinivasu Kunuku, Shiu-Cheng Lou, Joji Kurian, Huang-Chin Chen, Chi-Young Lee, Nyan-Hwa Tai, Keh-Chyang Leou, Chulung Chen and I-Nan Lin, "*Microplasma illumination enhancement of vertically aligned conducting ultrananocrystalline diamond nanorods*," [Nanoscale Research Letters](#), 7, 522 (2012) (Peer reviewed).

Impact Factor: [2.726](#).

9. Huang-Chin Chen, Kamatchi Jothiramalingam Sankaran, Shen-Chuan Lo, Li-Jiaun Lin, Nyan-Hwa Tai, Chi-Young Lee, and I-Nan Lin, "*Using an Au interlayer to enhance electron field emission properties of ultrananocrystalline diamond films*," [Journal of Applied Physics](#), 112, 103711 (2012) (Peer reviewed).

Impact Factor: [2.168](#).

10. K. J. Sankaran, H. C. Chen, C. Y. Lee, N. H. Tai, and I. N. Lin, "*Fabrication of free-standing highly conducting ultrananocrystalline diamond films with enhanced electron field emission properties*," [Applied Physics Letters](#), 101, 241604 (2012) (Peer reviewed).

Impact Factor: [3.844](#).

11. Jayakumar Shalini, Kamatchi Jothiramalingam Sankaran, Chung-Li Dong, Chi-Young Lee, Nyan-Hwa Tai, and I-Nan Lin, "*In situ detection of dopamine using nitrogen incorporated diamond nanowire electrode*," [Nanoscale](#), 5, 1159 (2013) (Peer reviewed).

Impact Factor: [5.914](#).

12. Jayakumar Shalini, Yi-Chieh Lin, Ting-Hsun Chang, Kamatchi Jothiramalingam Sankaran, Huang-Chin Chen, I.-Nan Lin, Chi-Young Lee, Nyan-Hwa Tai, and I-Nan Lin, "*Ultra-nanocrystalline diamond nanowires with enhanced electrochemical properties*," [Electrochimica Acta](#), 92, 9 (2013) (Peer reviewed).

Impact Factor: [3.777](#).

13. Kamatchi Jothiramalingam Sankaran, Yen-Fu Lin, Wen-Bin Jian, Huang-Chin Chen, Kalpataru Panda, Balakrishnan Sundaravel, Chung-Li Dong, Nyan-Hwa Tai and I-Nan Lin, "*Structural and electrical properties of conducting diamond nanowires*," [ACS Applied Materials and Interfaces](#), 5, 1294 (2013) (Peer reviewed).

Impact Factor: [5.008](#).

14. K. J. Sankaran, H. C. Chen, B. Sundaravel, C. Y. Lee, N. H. Tai, and I. N. Lin, "*Gold ion implantation induced high conductivity and enhanced electron field emission properties in ultrananocrystalline diamond films*," [Applied Physics Letters](#), 102, 061604 (2013) ([Research Highlights of APL](#)) (Peer reviewed).

Impact factor: [3.794](#).

15. Kamatchi Jothiramalingam Sankaran, Joji Kurian, Niranjana Kumar, Huang-Chin Chen, Ashok Kumar Tyagi, Sitaram Dash, Chi-Young Lee, Nyan-Hwa Tai and I-Nan Lin,

- “Improvement in Tribological Properties by Modification of Grain Boundary and Microstructure of Ultrananocrystalline Diamond Films,” ACS Applied Materials and Interfaces, 5, 3614 (2013) (Peer reviewed).*
Impact Factor: [5.008](#).
16. K. J. Sankaran, N. Kumar, S. Dash, H. C. Chen, A. K. Tyagi, N. H. Tai, and I. N. Lin, *“Significance of grain and grain boundary phases on the tribological behavior of ultrananocrystalline diamond films,” Surface and Coatings Technology, 232, 75 (2013) (Peer reviewed).*
Impact factor: [1.941](#).
17. N. Kumar, Radhika Ramadoss, A. T. Kozakov, K. J. Sankaran, S. Dash, A. K. Tyagi, N. H. Tai and I-Nan Lin, *“Humidity-dependent friction mechanism in an ultrananocrystalline diamond film,” Journal of Physics D: Applied Physics, 46, 275501 (2013) (Peer reviewed).*
Impact factor: [2.528](#).
18. Srinivasu Kunuku, Kamatchi Jothiramalingam Sankaran, Cheng-Yen Tsai, Wen-Hao Chang, Nyan-Hwa Tai, Keh-Chyang Leou, and I-Nan Lin, *“Investigations on Diamond Nanostructuring of Different Morphologies by the Reactive-Ion Etching Process and Their Potential Applications,” ACS Applied Materials and Interfaces, 5, 7439 (2013) (Peer reviewed).*
Impact factor: [5.008](#).
19. K. J. Sankaran, K. Srinivasu, H. C. Chen, C. L. Dong, K. C. Leou, C. Y. Lee, N. H. Tai, and I. N. Lin, *“Improvement in plasma illumination properties of ultrananocrystalline diamond films by grain boundary engineering,” Journal of Applied Physics, 114, 054304 (2013) (Peer reviewed).*
Impact factor: [2.210](#).
20. Kamatchi Jothiramalingam Sankaran, Niranjana Kumar, Huang-Chin Chen, Chung-Li Dong, Ashok Bahuguna, Sitaram Dash, Ashok Kumar Tyagi, Chi-Young Lee, Nyan-Hwa Tai, and I-Nan Lin, *“Near Frictionless Behavior of Hydrogen Plasma Treated Diamond Nanowire Films,” Science of Advanced Materials, 5, 1, (2013) (Peer reviewed).*
Impact factor: [2.509](#).
21. R. Radhika, N. Kumar, K. J. Sankaran, R. Dumpala, S. Dash, M. S. R. Rao, D. Arivuoli, A.K. Tyagi, N. H. Tai, I-Nan Lin, *“Extremely high wear resistance and ultra-low friction behavior of oxygen-plasma treated nanocrystalline diamond films,” Journal of Physics D: Applied Physics, 46, 425304 (2013) (Peer reviewed).*
Impact factor: [2.528](#).
22. K. J. Sankaran, K. Srinivasu, K. C. Leou, N. H. Tai, and I. N. Lin, *“High stability electron field emitters made of nanocrystalline diamond coated carbon nanotubes,” Applied Physics Letters, 103, 251601 (2013) (Peer reviewed).*

Impact factor: [3.794](#).

23. Kamatchi Jothiramalingam Sankaran, Manekkathodi Afsal, Shiu-Cheng Lou, Huang-Chin Chen, Chulung Chen, Chi-Young Lee, Lih-Juann Chen, Nyan-Hwa Tai and I-Nan Lin, “*Electron field emission enhancement of vertically aligned ultrananocrystalline diamond coated ZnO core-shell heterostructured nanorods*,” [Small](#), 10, 179 (2014) (Peer reviewed).

Impact Factor: [7.823](#).

24. Jayakumar Shalini, Kamatchi Jothiramalingam Sankaran, Huang-Chin Chen, Chi-Young Lee, Nyan- Hwa Tai, and I-Nan Lin, “*Mediatorless N₂ incorporated Diamond Nanowire Electrode for Selective Detection of NADH at Stable Low Oxidation Potential*,” [Analyst](#), 139, 778 (2014) (Peer reviewed).

Impact factor: [3.969](#).

25. Jayakumar Shalini, Kamatchi Jothiramalingam Sankaran, Huang-Chin Chen, Chi-Young Lee, Nyan- Hwa Tai, and I-Nan Lin, “*An Amperometric Urea Biosensor based on Covalent Immobilization of Urease on N₂ Incorporated Diamond Nanowire Electrode*,” [Biosensors and Bioelectronics](#), 56, 64 (2014) (Peer reviewed).

Impact factor: [6.451](#).

26. Radhika Ramadoss, Niranjana Kumar, Kamatchi Jothiramalingam Sankaran, Pankaj Das, T. R. Ravindran, Sitaram Dash, Ashok Kumar Tyagi, Nyan-Hwa Tai, and I-Nan Lin, “*Temperature Dependent Tribological Studies and Phase Transformation in Ultra-Nanocrystalline Diamond Films*”, [Science of Advanced Materials](#), 6, 1 (2014) (Peer reviewed).

Impact factor: [2.509](#).

27. K. J. Sankaran, N. H. Tai, and I. N. Lin, “*Flexible electron field emitters fabricated using conducting ultrananocrystalline diamond pyramidal microtips on polynorbornene films*,” [Applied Physics Letters](#), 104, 031601 (2014) (Peer reviewed).

Impact factor: [3.794](#).

28. K. J. Sankaran, K. Panda, B. Sundaravel, N. H. Tai, and I. N. Lin, “*Enhancing electrical conductivity and electron field emission properties of ultrananocrystalline diamond films by copper ion implantation and annealing*,” [Journal of Applied Physics](#), 115, 063701 (2014) (Peer reviewed).

Impact factor: [2.210](#).

29. Kamatchi Jothiramalingam Sankaran, Huang Chin Chen, Kalpataru Panda, Balakrishnan Sundaravel, Chi-Young Lee, Nyan-Hwa Tai, and I-Nan Lin, “*Enhanced Electron Field Emission Properties of Conducting Ultrananocrystalline Diamond Films after Cu and Au Ion Implantations*,” [ACS Applied Materials and Interfaces](#), 6, 4911 (2014) (Peer reviewed).

Impact factor: [5.008](#).

30. A. Saravanan, B. R. Huang, K. J. Sankaran, C. L. Dong, N. H. Tai, and I. N. Lin, “*Fast growth of ultrananocrystalline diamond films by bias-enhanced nucleation and growth process in CH₄/Ar plasma,*” [Applied Physics Letters](#), 104, 181603 (2014) (Peer reviewed).
Impact factor: [3.794](#).
31. Kalpataru Panda, Kamatchi Jothiramalingam Sankaran, Binaya Kumar Panigrahi, Nyan-Hwa Tai, and I-Nan Lin, “*Direct Observation and Mechanism for Enhanced Electron Emission in Hydrogen Plasma-Treated Diamond Nanowire Films,*” [ACS Applied Materials and Interfaces](#), 6, 8531 (2014) (Peer reviewed).
Impact factor: [5.008](#).
32. Tinghsun Chang, Srinivasu Kunuku, Kamatchi Jothiramalingam Sankaran, Keh-Chyang Leou, Nyan-Hwa Tai, and I-Nan Lin, “*Enhancing the stability of microplasma device utilizing diamond coated carbon nanotubes as cathode materials,*” [Applied Physics Letters](#), 104, 223106 (2014) (Peer reviewed).
Impact factor: [3.794](#).
33. Adhimoorthy Saravanan, Bohr-Ran Huang, Kamatchi Jothiramalingam Sankaran, Srinivasu Kunuku, Chung-Li Dong, Keh-Chyang Leou, Nyan-Hwa Tai, and I-Nan Lin, “*Bias-enhanced Nucleation and Growth Processes for Ultrananocrystalline Diamond Films in Ar/CH₄ Plasma and Their Enhanced Plasma Illumination Properties,*” [ACS Applied Materials and Interfaces](#), 6, 10566 (2014) (Peer reviewed).
Impact factor: [5.008](#).
34. R. Radhika, N. Kumar, A.T. Kozakov, K.J. Sankaran, S. Dash, A.K. Tyagi, N.-H. Tai, I.N. Lin, “*Role of transfer layer on tribological properties of nanocrystalline diamond nanowire film sliding against alumina allotropes,*” [Diamond and Related Materials](#), 48, 6 (2014) (Peer reviewed).
Impact factor: [1.709](#).
35. Marie Jakl Krecmarová, Václav Petrák, Andrew Taylor, Kamatchi Jothiramalingam Sankaran, I-Nan Lin, Aleš Jäger, Viera Gärtnerová, Ladislav Fekete, Jan Drahoukoupil, František Laufek, Jirí Vacík, Pavel Hubík, Vincent Mortet, and Miloš Nesládek, “*Change of diamond film structure and morphology with N₂ addition in MW PECVD apparatus with linear antenna delivery system,*” [Phys. Status Solidi A](#), 211, 2296 (2014) (Peer reviewed).
Impact factor: [1.469](#).
36. Kamatchi Jothiramalingam Sankaran, Srinivasu Kunuku, Keh-Chyang Leou, Nyan-Hwa Tai, and I-Nan Lin, “*Enhancement of the Electron Field Emission Properties of Ultrananocrystalline Diamond Films via Hydrogen Post-Treatment,*” [ACS Applied Materials and Interfaces](#), 6, 14543 (2014) (Peer reviewed).
Impact factor: [5.900](#).
37. Joji Kurian, Kamatchi Jothiramalingam Sankaran, Joseph P. Thomas, N. H. Tai, Huang-Chin

Chen¹ and I-Nan Lin, “*The role of nanographitic phase on enhancing the electron field emission properties of hybrid granular structured diamond films-the electron energy loss spectroscopic studies,*” [Journal of Physics D: Applied Physics](#), 47, 415303 (2014) (Peer reviewed).

Impact factor: [2.521](#).

38. Joji Kurian, Kamatchi Jothiramalingam Sankaran, and I-Nan Lin, “*On the role of graphite in ultrananocrystalline diamond films used for electron field emitter applications,*” [physica status solidi \(a\)](#), 211, 2223 (2014) (feature article).

Impact factor: [1.469](#).

39. Srinivasu Kunuku, Kamatchi Jothiramalingam Sankaran, Chungli Dong, Nyan-Hwa Tai, Keh-Chyang Leou, and I-Nan Lin, “*Development of long lifetime cathode materials for microplasma application,*” [RSC Advances](#), 4, 47865 (2014) (Peer reviewed).

Impact factor: [3.708](#).

40. Kalpataru Panda, Kamatchi J. Sankaran, Eiichi Inami, Yoshiaki Sugimoto, Nyan Hwa Tai, I-Nan Lin, “*Direct observation and mechanism for enhanced field emission sites in platinum ion implanted/post-annealed ultrananocrystalline diamond films,*” [Applied Physics Letters](#), 105, 163109 (2014) (Peer reviewed).

Impact factor: [3.794](#).

41. K. J. Sankaran, B. R. Huang, A. Saravanan, N. H. Tai, and I. N. Lin, “*Origin of graphitic filaments on improving the electron field emission properties of negative bias-enhanced grown ultrananocrystalline diamond films in CH₄/Ar plasma,*” [Journal of Applied Physics](#), 116, 163102 (2014) (Peer reviewed).

Impact factor: [2.185](#).

42. Kamatchi Jothiramalingam Sankaran, Kalpataru Panda, Sundaravel Balakrishnan, Nyan-Hwa Tai, and I-Nan Lin, “*Catalytically induce nanographite phase by platinum-ion implantation/annealing process to improve the field electron emission properties of ultrananocrystalline diamond films,*” [Journal of Materials Chemistry C](#), 3, 2632 (2015) (Peer reviewed).

Impact factor: [6.626](#).

43. Kamatchi Jothiramalingam Sankaran, Srinivasu Kunuku, Sundaravel Balakrishnan, Ping-Yen Hsieh, Huang-Chin Chen, Keh-Chyang Leou, Nyan-Hwa Tai, and I-Nan Lin, “*Gold nanoparticles-ultrananocrystalline diamond hybrid structured materials for high-performance optoelectronic device applications,*” [Nanoscale](#), 7, 4377 (2015) (Peer reviewed).

Impact factor: [6.739](#).

44. K. J. Sankaran, N. H. Tai, and I. N. Lin, “*Microstructural evolution of diamond films from CH₄/H₂/N₂ plasma and their enhanced electrical properties,*” [Journal of Applied Physics](#),

117, 075303 (2015) (Peer reviewed).

Impact factor: [2.185](#).

45. A. Saravanan, B. R. Huang, K. J. Sankaran, C. L. Dong, N. H. Tai, and I. N. Lin, “*Bias-enhanced post-treatment process for enhancing the electron field emission properties of ultrananocrystalline diamond films*,” [Applied Physics Letters](#), 106, 111602 (2015) (Peer reviewed).

Impact factor: [3.794](#).

46. A. Saravanan, B. R. Huang, K. J. Sankaran, Gerd Keiser, Joji Kurian, N. H. Tai, and I. N. Lin, “*Structural modification of nanocrystalline diamond films via positive/negative bias enhanced nucleation and growth processes for improving their electron field emission properties*,” [Journal of Applied Physics](#), 117, 215307 (2015) (Peer reviewed).

Impact factor: [2.185](#).

47. Adhimoorthy Saravanan, Bohr-Ran Huang, Kamatchi Jothiramalingam Sankaran, Nyan-Hwa Tai, and I-Nan Lin, “*Highly Conductive Diamond–Graphite Nanohybrid Films with Enhanced Electron Field Emission and Microplasma Illumination Properties*,” [ACS Applied Materials and Interfaces](#), 7, 14035 (2015) (Peer reviewed).

Impact factor: [6.723](#).

48. K. J. Sankaran, B. Sundaravel, N. H. Tai, and I. N. Lin, “*Improvement on electrical conductivity and electron field emission properties of Au-ion implanted ultrananocrystalline diamond films by using Au-Si eutectic substrates*,” [Journal of Applied Physics](#), 118, 085306 (2015) (Peer reviewed).

Impact factor: [2.185](#).

49. Revati Rani, N. Kumar, A.T. Kozakov, K. A. Googlev, K.J. Sankaran, Pankaj Kr. Das, S. Dash, A.K. Tyagi, I.N. Lin, “*Superlubrication properties of ultrananocrystalline diamond film sliding against the zirconia ball*,” [RSC Advances](#), 5(122), 100663 (2015) (Peer reviewed).

Impact factor: [3.84](#).

50. Kamatchi Jothiramalingam Sankaran, Bohr-Ran Huang, Adhimoorthy Saravanan, Divinah Manoharan, Nyan-Hwa Tai, and I-Nan Lin, “*Heterostructured Diamond–Gold Nanohybrids: A New Long-Life Electronic Display Cathode*”, [ACS Applied Materials and Interfaces](#), 7, 27078 (2015) (Peer reviewed).

Impact factor: [6.723](#).

51. Kamatchi Jothiramalingam Sankaran, Bohr-Ran Huang, Adhimoorthy Saravanan, Divinah Manoharan, Nyan-Hwa Tai, and I-Nan Lin, “*Nitrogen Incorporated Ultrananocrystalline Diamond Microstructures from Bias-enhanced Microwave N₂/CH₄-Plasma Chemical Vapor Deposition*”, [Plasma Processes and Polymers](#), 13, 419 (2016) (Peer reviewed).

Impact factor: [2.453](#).

52. Mateusz Ficek, Kamatchi J. Sankaran, Jacek Ryl, Robert Bogdanowicz, I-Nan Lin, Ken Haenen, and Kazimierz Darowicki, “*Ellipsometric investigation of nitrogen doped diamond thin films grown in microwave CH₄/H₂/N₂ plasma enhanced chemical vapor deposition*”, [Applied Physics Letters](#), 108, 241906 (2016) (Peer reviewed).
Impact factor: [3.142](#).
53. Kamatchi Jothiramalingam Sankaran, Ting-Hsun Chang, Santosh Kumar Bikkarolla, Susanta Sinha Roy, Pagona Papakonstantinou, Sien Drijckoningen, Paulius Pobedinskas, Marlies Van Bael, Nyan-Hwa Tai, I-Nan Lin and Ken Haenen, “*Growth, structural and plasma illumination properties of nanocrystalline diamond decorated graphene nanoflakes*” [RSC Advances](#), 6, 63178 (2016) (Peer reviewed).
Impact factor: [3.289](#).
54. Kamatchi Jothiramalingam Sankaran, Hoang Duc Quang, Srinivasu Kunuku, Svetlana Korneychuk, Stuart Turner, Paulius Pobedinskas, Sien Drijckoningen, Marlies Van Bael, Jan D’Haen, Johan Verbeeck, Keh-Chyang Leou, I-Nan Lin and Ken Haenen, “*Enhanced optoelectronic performances of vertically aligned hexagonal boron nitride nanowalls-nanocrystalline diamond heterostructures*” [Scientific Reports](#), 6, 29444 (2016) (Peer reviewed).
Impact factor: [5.228](#).
55. K. J. Sankaran, D. Manoharan, B. Sundaravel, and I. N. Lin, “*Multienergy gold ion implantation for enhancing the field electron emission characteristics of heterostructured diamond films grown on Au-coated Si substrates*” [Applied Physics Letters](#), 109, 101603 (2016) (Peer reviewed).
Impact factor: [3.142](#).
56. Kamatchi Jothiramalingam Sankaran, Duc Quang Hoang, Svetlana Korneychuk, Srinivasu Kunuku, Joseph Palathinkal Thomas, Paulius Pobedinskas, Sien Drijckoningen, Marlies K. Van Bael, Jan D’Haen, Johan Verbeeck, Keh-Chyang Leou, Kam Tong Leung, I-Nan Lin, and Ken Haenen, “*Hierarchical hexagonal boron nitride nanowall–diamond nanorod heterostructures with enhanced optoelectronic performance*” [RSC Advances](#), 6, 90338 (2016) (Peer reviewed).
Impact factor: [3.289](#).
57. K. J. Sankaran, D. Q. Hoang, K. Srinivasu, S. Korneychuk, S. Turner, S. Drijckoningen, P. Pobedinskas, J. Verbeeck, K. C. Leou, I. N. Lin and K. Haenen, “*Engineering the interface characteristics on the enhancement of field electron emission properties of vertically aligned hexagonal boron nitride nanowalls*” [physica status solidi \(a\)](#) 10, 2654 (2016) (Peer reviewed).
Impact factor: [1.648](#).

58. Kalpataru Panda, Eiichi Inami, Yoshiaki Sugimoto, K. J. Sankaran and I-Nan Lin, “*Straight Imaging and Mechanism behind Grain Boundary Electron Emission in Pt-doped Ultrananocrystalline Diamond Films*” [Carbon](#), 111, 8 (2017) (Peer reviewed).
Impact factor: [6.198](#).
59. Kamatchi Jothiramalingam Sankaran, Chien-Jui Yeh, Sien Drijkoningen, Paulius Pobedinskas, Marlies K. Van Bael, Keh-Chyang Leou, I-Nan Lin and Ken Haenen, “*Enhancement of plasma illumination characteristics of few-layer graphene–diamond nanorods hybrid*” [Nanotechnology](#), 28, 065701 (2017) (Peer reviewed).
Impact factor: [3.573](#)
60. Duc-Quang Hoang, Svetlana Korneychuk, Kamatchi Jothiramalingam Sankaran, Paulius Pobedinskas, Sien Drijkoningen, Stuart Turner, Marlies K. Van Bael, Johan Verbeeck, Shannon S. Nicley, Ken Haenen, “*Direct nucleation of hexagonal boron nitride on diamond: Crystalline properties of hBN nanowalls*” [Acta Materialia](#), 127, 17 (2017) (Peer reviewed).
Impact factor: [5.058](#)
61. Srinivasu Kunuku, Kamatchi Jothiramalingam Sankaran, Keh-Chyang Leou and I-Nan Lin, “*Microplasma device architectures with various diamond nanostructures*” [Materials Research Express](#), 4, 025001 (2017) (Peer reviewed).
Impact factor: [0.968](#)
62. K. J. Sankaran, K. Srinivasu, C. J. Yeh, J. P. Thomas, S. Drijkoningen, P. Pobedinskas, B. Sundaravel, K. C. Leou, K. T. Leung, M. K. Van Bael, M. Schreck, I. N. Lin, K. Haenen, “*Field electron emission enhancement in lithium implanted and annealed nitrogen-incorporated nanocrystalline diamond films*” [Applied Physics Letters](#) 110, 261602 (2017) (Peer reviewed).
Impact factor: [3.411](#).
63. R. Ramaneti, K. J. Sankaran, S. Korneychuk, C. J. Yeh, G. Degutis, K. C. Leou, J. Verbeeck, M. K. Van Bael, I. N. Lin, K. Haenen, “*Vertically aligned diamond-graphite hybrid nanorod arrays with superior field electron emission properties*” [APL Materials](#) 5, 066102 (2017) (Peer reviewed) (R. Ramaneti and K. J. Sankaran contributed equally to this work).
Impact factor: [4.323](#).
64. G. Bhattacharya, K. J. Sankaran, S. B. Srivastava, J. P. Thomas, S. Deshmukh, P. Pobedinskas, S. P. Singh, K. T. Leung, M. K. Van Bael, K. Haenen, S. S. Roy, “*Probing the flat band potential and effective electronic carrier density in vertically aligned nitrogen doped diamond nanorods via electrochemical method*” [Electrochimica Acta](#) 246, 68 (2017) (Peer reviewed).
Impact factor: [4.803](#).

65. Kalpataru Panda, Jeong Jin Hyeok, Jeong Young Park, Kamatchi Jothiramalingam Sankaran, Sundaravel Balakrishnan and I.-Nan Lin, “*Nanoscale investigation of enhanced electron field emission for silver ion implanted/postannealed ultrananocrystalline diamond films*”, [Scientific Reports](#), 7, 16325 (2017) (Peer reviewed).
Impact factor: [5.228](#).
66. K. K. Mishra, Revati Rani, N. Kumar, T. R. Ravindran, K. J. Sankaran, I-Nan Lin, “*High pressure Raman spectroscopic studies on ultrananocrystalline diamond thin films: Anharmonicity and thermal properties of the grain boundary*”, [Diamond and Related Materials](#) 80, 45 (2017) (Peer reviewed).
Impact factor: [2.561](#).
67. Revati Rani, K. J. Sankaran, Kalpataru Panda, N. Kumar, K. Ganesan, S. Chakravarty, I-Nan Lin, “*Tribofilm formation in ultrananocrystalline diamond film*”, [Diamond and Related Materials](#) 78, 12 (2017) (Peer reviewed).
Impact factor: [2.561](#).
68. Revati Rani, Kalpataru Panda, Niranjana Kumar, Kamatchi Jothiramalingam Sankaran, K. Ganesan and I-Nan Lin, “*Tribological Properties of Ultrananocrystalline Diamond Films in Inert and Reactive Tribo-Atmospheres: XPS Depth-Resolved Chemical Analysis*”, [Journal of Physical Chemistry C](#), 122, 8602 (2018) (Peer reviewed).
Impact factor: [4.536](#).
69. S. Deshmukh, K. J. Sankaran, K. Srinivasu, S. Korneychuk, D. Banerjee, A. Barman, G. Bhattacharya, D. M. Phase, M. Gupta, J. Verbeeck, K. C. Leou, I. N. Lin, K. Haenen, S. S. Roy, “*Local probing of the enhanced field electron emission of vertically aligned nitrogen-doped diamond nanorods and their plasma illumination properties*”, [Diamond and Related Materials](#) 83, 118 (2018) (Peer reviewed) (S. Deshmukh and K. J. Sankaran contributed equally to this work).
Impact factor: [2.561](#).
70. Daria Majchrowicz, Monika Kosowska, Kamatchi J. Sankaran, Przemysław Struk, Michał Wałowicz, Michał Sobaszek, Ken Haenen and Małgorzata Jedrzejewska-Szczerska, “*Nitrogen-Doped Diamond Film for Optical Investigation of Hemoglobin Concentration*” [Materials](#), 11, 109 (2018) (Peer reviewed).
Impact factor: [2.654](#).
71. Revati Rani, Kalpataru Panda, Niranjana Kumar, Kamatchi Jothiramalingam Sankaran, Ramanathaswamy Pandian, Mateusz Ficek, Robert Bogdanowicz, Ken Haenen, and I-Nan Lin, “*Tribo-Environment Dependent Chemical Modification of Sliding Interfaces in Ultrananocrystalline Diamond Nanowall Film: A Correlation with Friction and Wear*”, [Journal of Physical Chemistry C](#), 122, 945 (2018) (Peer reviewed).
Impact factor: [4.536](#).

72. Kamatchi Jothiramalingam Sankaran, Mateusz Ficek, Srinivasu Kunuku, Kalpataru Panda, Chien-Jui Yeh, Jeong Young Park, Mirosław Sawczak, Paweł Piotr Michałowski, Keh-Chyang Leou, Robert Bogdanowicz, I-Nan Lin and Ken Haenen, “*Self-organized multi-layered graphene–boron doped diamond hybrid nanowalls for high performance electron emission devices*”, [Nanoscale](#), 10, 1345 (2018) (Peer reviewed).
Impact factor: [7.367](#).
73. Sujit Deshmukh, Kamatchi Jothiramalingam Sankaran, Svetlana Korneychuk, Johan Verbeeck, James McLaughlin, Ken Haenen and Sustanta Sinha Roy, “*Nanostructured nitrogen doped diamond for the detection of toxic metal ions*”, [Electrochimica Acta](#), 283, 1871 (2018) (Peer reviewed).
Impact factor: [5.116](#).
74. Marzena Hirsch, Monika Kosowska, Daria Majchrowicz, Przemysław Struk, Paweł Wierzba, Mateusz Ficek, Kamatchi J. Sankaran, Ken Haenen, and Małgorzata Jędrzejewska-Szczerska, “*Low-Coherence Interferometer with Nanocrystalline Diamond Films with Potential Application to Measure Small Biological Samples*”, [physica status solidi \(a\)](#), 1800244, 1 (2018).
Impact factor: [1.45](#).
75. Kamatchi Jothiramalingam Sankaran, Sujit Deshmukh, Svetlana Korneychuk, Chien-Jui Yeh, Joseph Palathinkal Thomas, Sien Drijkoningen, Paulius Pobedinskas, Marlies K. Van Bael, Johan Verbeeck, Keh-Chyang Leou, Kam-Tong Leung, Susanta Sinha Roy, I-Nan Lin, and Ken Haenen, “*Fabrication, microstructure and enhanced thermionic electron emission properties of vertically aligned nitrogen-doped nanocrystalline diamond nanorods*”, [MRS Communications](#), 8, 1131 (2018) (Peer reviewed).
Impact factor: [3.008](#).
76. K. J. Sankaran, K. Srinivasu, C. J. Yeh, J. P. Thomas, P. Pobedinskas, S. Drijkoningen, B. Sundaravel, K. C. Leou, K. T. Leung, M. K. Van Bael, M. Schreck, I. N. Lin, K. Haenen, “*Microstructural effect on the enhancement of field electron emission properties of nanocrystalline diamond films by Li-ion implantation and annealing processes*”, [ACS Omega](#) 3, 9956 (2018) (Peer reviewed).
77. Kamatchi Jothiramalingam Sankaran, Kalpataru Panda, Ping-Yen Hsieh, Paulius Pobedinskas, Jeong Young Park, Marlies K Van Bael, Nyan-Hwa Tai, I-Nan Lin and Ken Haenen, “*Low Temperature Synthesis of Lithium-Doped Nanocrystalline Diamond Films with Enhanced Field Electron Emission Properties*”, [Nanomaterials](#), 8, 653 (2018) (Peer reviewed).
Impact factor: [3.811](#).
78. Jerome A. Cuenca, Kamatchi Jothiramalingam Sankaran, Paulius Pobedinskas, Kalpataru Panda, I-Nan Lin, Adrian Porch, Ken Haenen, Oliver A. Williams, “*Microwave cavity*

perturbation of nitrogen doped nano-crystalline diamond films”, [Carbon](#), 145, 740 (2019) (Peer reviewed).

Impact factor: [7.082](#).

79. N. Kumar,, A. T. Kozakov,, K. J. Sankaran, A. V. Sidashov, I-Nan Lin, “*Controlled atmosphere dependent tribological properties of thermally annealed ultrananocrystalline diamond films*”, [Diamond and Related Materials](#) 97, 107437 (2019) (Peer reviewed).

Impact factor: [2.290](#).

80. Monika Kosowska, Daria Majchrowicz, Kamatchi J. Sankaran, Mateusz Ficek, Ken Haenen and Małgorzata Szczerska, “*Doped Nanocrystalline Diamond Films as Reflective Layers for Fiber-Optic Sensors of Refractive Index of Liquids*”, [Materials](#) 12, 2124 (2019) (Peer reviewed).

Impact factor: [2.972](#).

81. Debosmita Banerjee, Kamatchi Jothiramalingam Sankaran, Sujit Deshmukh, Mateusz Ficek, Gourav Bhattacharya, Jacek Ryl, Deodatta Maheshwar Phase, Mukul Gupta, Robert Bogdanowicz, I-Nan Lin, Alope Kanjilal, Ken Haenen, and Susanta Sinha Roy, “*3D Hierarchical Boron-Doped Diamond-Multilayered Graphene Nanowalls as an Efficient Supercapacitor Electrode*”, [J. Phys. Chem. C](#) 123, 15458 (2019) (Peer reviewed).

Impact factor: [4.484](#).

82. Sujit Deshmukh, Kamatchi Jothiramalingam Sankaran, Debosmita Banerjee, Chien-Jui Yeh, Key-Chyang Leou, Deodatta Maheshwar Phase, Mukul Gupta, I.-Nan Lin, Ken Haenen, Susanta Sinha Roy and Prashant R. Waghmare, “*Direct synthesis of electrowettable nanostructured hybrid diamond*”, [J. Mater. Chem. A](#) 7, 19026 (2019) (Peer reviewed).

Impact factor: [10.733](#).

83. Kamatchi Jothiramalingam Sankaran, Chien-Jui Yeh, Ping-Yen Hsieh, Paulius Pobedinskas, Srinivasu Kunuku, Keh-Chyang Leou, Nyan-Hwa Tai, I-Nan Lin and Ken Haenen, “*Origin of Conductive Nanocrystalline Diamond Nanoneedles for Optoelectronic Applications*”, [ACS Appl. Mater. Interfaces](#) 11, 25388 (2019) (Peer reviewed).

Impact factor: [8.456](#).

Total citations: 1076; H-index: 19 (source: Google scholar)

CONFERENCE PROCEEDINGS

1. Ting-Hsun Chang, Shiu-Cheng Lou, Nyan-Hwa Tai, Kamatchi Jothiramalingam Sankaran, Chulung Chen, and I-Nan Lin, “*Fabrication of nitrogen-doped ultrananocrystalline diamond nanowire arrays with enhanced field emission and plasma illumination performance*,” 9–13 July, 2012, Vacuum Nanoelectronics Conference (IVNC), 2012 25th International, Jeju, South Korea.

Citations: **1**.

2. Joji Kurian, Kamatchi Jothiramalingam Sankaran, Nyan-Hwa Tai, and I-Nan Lin, “*Selective area growth of highly resistive ultrananocrystalline diamond films using copper patterned silicon substrates*,” First National Conference on Advanced Nanomaterials- CAN 2015, 1 and 2, October, 2015, Department of Physics, Nirmalagiri College, Kannur, Kerala, India.
3. M. Kosowska, D. Majchrowicz, K. J. Sankaran, M. Ficek, M. J. Szczerka and K. Haenen, “*Nitrogen-doped diamond thin films: potential application in Fabry-Pérot interferometer*”, Proc. SPIE 10716, Saratov Fall Meeting 2017: Optical Technologies in Biophysics and Medicine XIX (Peer reviewed).

CONFERENCES AND SEMINARS PRESENTED/PARTICIPATED

1. Participated in the One-day Inter-collegiate Seminar on Solid State Physics, 19 October, 2002, Devanga Arts College, Aruppukottai, Tamil Nadu, India.
2. Participated in the One-day Inter-collegiate meet “NOVA ‘05”, 25 January 2005, Saiva Bhanu Kshatriya College, Aruppukottai, Tamil Nadu, India.
3. Participated in the International Workshop on Nanoscience and Technology, 13–17, February 2006, Department of Physics, College of Engineering, Anna University, Chennai, India.
4. Presented the paper “*Growth and characterization of Boric acid doped potassium dihydrogen phosphate crystals for non-linear optics applications*,” Second National Symposium on Nonlinear Optical Crystals and Modelling in Crystal Growth, 26–27 March, 2007, Department of Physics, College of Engineering, Anna University, Chennai, India (*Oral presentation*).
5. Participated in the Fourteenth National Congress on Corrosion Control, 18–20 September, 2008, Hotel Green Park, Hyderabad, India.
6. K. J. Sankaran, P. T. Joseph, H. C. Chen, N. H. Tai, and I. N. Lin, “*Investigation in the role of hydrogen on the growth and properties of diamond films using CH₄/Ar/H₂ microwave plasma*,” NDNC 2010, 16–20 May 2010, Suzhou, China (*Poster presentation*).

7. K. J. Sankaran, P. T. Joseph, H. C. Chen, N. H. Tai, and I. N. Lin, "*Investigation in the role of hydrogen on the properties of diamond films grown using CH₄/Ar/H₂ microwave plasma,*" MRS-T 2010, 19–20 November 2010, Kaohsiung, Taiwan (*Poster presentation*).
8. K. J. Sankaran, P. T. Joseph, H. C. Chen, N. H. Tai, and I. N. Lin, "*Influence of substrate temperature on ultrananocrystalline diamond films prepared using Ar/CH₄ plasma,*" 2011 AVS International Plasma Workshop, 22–25 March 2011, Taipei, Taiwan ([Best Poster Presentation Award](#)).
9. K. J. Sankaran, P. T. Joseph, H. C. Chen, N. H. Tai, and I. N. Lin, "*Enhanced field emission from performance of ultrananocrystalline diamond films on metallic patterned silicon chips*" New Diamond and Nano Carbons 2011, 16–20 May 2011, Matsue, Japan (*Poster presentation*).
10. K. J. Sankaran, K. Y. Teng, P. T. Joseph, K. Panda, B. Sundaravel, C. Y. Lee, N. H. Tai, and I. N. Lin, "*Structural and electrical properties of diamond nanowires from n-type ultrananocrystalline diamond films,*" Second International Conference on Nanomaterials (ICN 2012), 12–15 January 2012, Kottayam, Kerala, India (*Oral presentation*).
11. J. Kurian, K. J. Sankaran, H. C. Chen, C. L. Dong, C. Y. Lee, N. H. Tai, and I. N. Lin, "*Origin of a needle-like granular structure for ultrananocrystalline diamond films grown in a N₂/CH₄ plasma,*" 30st Symposium on Spectroscopic Technologies and Surface Sciences, 25–27 June 2012, Taiwan (*Oral presentation*).
12. K. Srinivasu, K. J. Sankaran, J. Kurian, C. Y. Lee, N. H. Tai, I. N. Lin and K. C. Leou, "*Diamond nanostructuring by Reactive ion etching method in O₂/CF₄ plasma*", IS Plasma 2013, 28 January–1 February 2013, Nagoya University, Japan (*Poster presentation*).
13. Ting-Hsun Chang, Shiu-Cheng Lou, Nyan-Hwa Tai, Kamatchi Jothiramalingam Sankaran, Chulung Chen, and I-Nan Lin, "*Fabrication of nitrogen-doped ultrananocrystalline diamond nanowire arrays with enhanced field emission and plasma illumination performance,*" Vacuum Nanoelectronics Conference (IVNC), 2012 25th International, 9–13 July, 2012, Jeju, South Korea (*Poster presentation*).
14. K. J. Sankaran, K. Panda, B. Sundaravel, H. C. Chen, I. N. Lin, C. Y. Lee, and N. H. Tai, "*Engineering the Interface Characteristics of Ultrananocrystalline Diamond Films Grown on Au-Coated Si Substrates,*" 30st Symposium on Spectroscopic Technologies and Surface Sciences, 25–27 June 2013, Taiwan (*Poster presentation*).
15. K. J. Sankaran, M. Afsal, S. C. Lou, H. C. Chen, C. Chen, C. Y. Lee, L. J. Chen, N. H. Tai, and I. N. Lin, "*Electron field emission enhancement of vertically aligned ultrananocrystalline diamond coated ZnO core-shell heterostructured nanorods,*" TACT 2013 International Students Symposium on Thin Films and Coatings, 30 March 2013, Hsinchu, Taiwan ([Best Poster Presentation Award](#)).

16. K. J. Sankaran, M. Afsal, S. C. Lou, H. C. Chen, C. Chen, C. Y. Lee, L. J. Chen, N. H. Tai, and I. N. Lin, “*Electron field emission enhancement of ultrananocrystalline diamond/ ZnO thin film heterojunction*,” New Diamond and Nano Carbons 2013, 19–23 May 2013, Novotel Clarke Quay, Singapore (*Poster presentation*).
17. Shalini Jayakumar, K. J. Sankaran, C. Y. Lee, N. H. Tai, and I. N. Lin, “*Functionalized N₂-incorporated diamond nanowire electrode as urea biosensor*,” New Diamond and Nano Carbons 2013, 19–23 May 2013, Novotel Clarke Quay, Singapore (*Poster presentation*).
18. K. J. Sankaran, H. C. Chen, B. Sundaravel, C. Y. Lee, N. H. Tai, and I. N. Lin, “*Mechanism of electron field emission enhancement for ultrananocrystalline diamond films due to ion implantation*,” 31st Symposium on Spectroscopic Technologies and Surface Sciences, 23–25 July 2013, Taiwan (*Oral presentation*).
19. K. J. Sankaran, H. C. Chen, B. Sundaravel, C. Y. Lee, N. H. Tai, and I. N. Lin, “*Copper ion implantation for the enhancement of electron field emission enhancement of ultrananocrystalline diamond films*,” IEEE NMDC, 6–9 October 2013, Taiwan (*Oral presentation*).
20. Shalini Jayakumar, Kamatchi Jothiramalingam Sankaran, Chi-Young Lee, Nyan-Hwa Tai, and I-Nan Lin, “*Simultaneous Detection of Toxic Metal Ion Using Samarium Hexacyanoferrate Nanoparticles Modified Diamond Nanowires Electrode as an Electro-Chemical Sensor*”, 2013 MRS Fall Meeting & Exhibit, 1–6, December 2013, Boston, Massachusetts (*Poster presentation*).
20. A. Saravanan, K. Srinivasu, K. J. Sankaran, N. H. Tai, K. C. Leou, B.R Huang and I. N. Lin, “*Growth of Ultrananocrystalline Diamond films by Bias Enhanced Growth in the Microwave Plasma Enhanced Chemical Vapor Deposition System*”, 8th Asia-Pacific International Symposium on the Basics and Applications of Plasma Technology 2013, 20–22, December 2013, Hsinchu, Taiwan (*Poster presentation*).
21. K. Srinivasu, K. J. Sankaran, N. H. Tai, K. C. Leou, and I. N. Lin, “*Plasma for Growth, Processing of Diamond films and Diamond Nanostructures for Microplasma Applications*”, 8th Asia-Pacific International Symposium on the Basics and Applications of Plasma Technology 2013, 20–22, December 2013, Hsinchu, Taiwan (*Oral presentation*).
22. K. Srinivasu, K. J. Sankaran, C. L Dong, N. H. Tai, K. C. Leou and I. N. Lin, “*Diamond films with different granular structures grown on Au coated Si for application of micro discharges and their characteristics*”, TACT 2014 International Students Symposium on Thin Films and Coatings, 29 March 2014, Tainan, Taiwan (*Oral Presentation Award 3rd Winner*).
23. K. J. Sankaran, H. C. Chen, K. Panda, B. Sundaravel, C. Y. Lee, N. H. Tai, and I. N. Lin, “*Enhanced Electron Field Emission Properties of Conducting Ultrananocrystalline Diamond Films after Cu and Au Ion Implantations*”, TACT 2014 International Students Symposium on Thin Films and Coatings, 29 March 2014, Tainan, Taiwan (*Oral Presentation Award 1st Winner*).
24. K. Panda, Eiichi Inami, K. J Sankaran, Yoshiaki Sugimoto, Nyan-Hwa Tai, I-Nan Lin,

- “Combined STM and AFM study on the mechanism for enhanced electron emission in Pt ion implanted UNCD films”* 17th International Conference on non-contact Atomic Force Microscopy, 4–8 August 2014, Tsukuba, Japan (*Poster presentation*).
25. M. Jakl Krečmarová, V. Petrák, A. Taylor, L. Fekete, K. J. Sankaran, I-Nan Lin, V. Gärtnerová, A. Jäger, J. Drahekoupil, V. Mortet and M. Nesládek, *“Linear antenna microwave plasma CVD diamond deposition: effect of nitrogen addition into the gas phase,”* International Conference on Diamond and Carbon Materials, 7–11 September, 2014, Madrid, Spain (*Poster presentation*).
 26. Adhimoorthy Saravanan, Bohr-Ran Huang, Kamatchi Jothiramalingam Sankaran, Srinivasu Kunuku, Chung-Li Dong, Keh-Chyang Leou, Nyan-Hwa Tai, and I-Nan Lin, *“Investigation on the bias-enhanced nucleation and growth processes of ultrananocrystalline diamond films (UNCD) and their enhanced electron field emission and plasma illumination properties,”* 7th Vacuum and Surface Sciences Conference of Asia and Australia, 5–9 October 2014, Hsinchu Taiwan (*Oral Presentation*).
 27. K. J. Sankaran, B. Sundaravel, P. Y. Hsieh, N. H. Tai, I. N. Lin, *“The improvement of electrical conductivity and electron field emission properties of Au-ion implanted ultrananocrystalline diamond films by using Au-Si eutectic substrates,”* 7th Vacuum and Surface Sciences Conference of Asia and Australia, 5–9 October 2014, Hsinchu Taiwan (*Oral Presentation*).
 28. K. Panda, Eiichi Inami, K. J. Sankaran, Yoshiaki Sugimoto, Nyan-Hwa Tai, I-Nan Lin, *“Direct Observation of Enhanced Electron Emission Sites in Pt Ion Implanted/Post-annealed Ultra nanocrystalline Diamond Films”*, The 7th International Symposium on Surface Science, 2–6 November 2014, Matsue, Shimane, Japan (*Best Poster Presentation Award*).
 29. K. J. Sankaran, *“Ultrananocrystalline Diamond Films for Electron Field Emitter Applications”*, International Conference on Recent Trends in Materials, 22 and 23 December 2014, Devanga Arts College, Aruppukottai, Tamilnadu, India (*Invited Talk*).
 30. A. Saravanan, B. R. Huang, K. J. Sankaran, N. H. Tai, and I. N. Lin, *“Bias-enhanced post-treatment process for enhancing the electron field emission properties of ultrananocrystalline diamond films”*, Hasselt Diamond Workshop 2015-SBDD XX, 20–22, February 2015, Hasselt, Belgium (*Poster presentation*).
 31. K. J. Sankaran, B. Sundaravel, N. H. Tai, K. Haenen, I. N. Lin, *“Gold nanoparticles-ultrananocrystalline diamond hybrid structured materials for high-performance electronic device applications,”* Hasselt Diamond Workshop 2015-SBDD XX, 20–22, February 2015, Hasselt, Belgium (*Poster presentation*).
 32. Sheng Chang Lin, Chien-Jui Yeh, Joji Kurian, K. J. Sankaran, Keh-Chyang Leou, and I. N. Lin, *“The application of hybrid granular structure diamond films for microplasma*

- applications*,” Hasselt Diamond Workshop 2015-SBDD XX, 20–22 February 2015, Hasselt, Belgium (*Poster presentation*).
33. K. Panda, E. Inami, K. J Sankaran, Y. Sugimoto, N. H. Tai, I. N. Lin, “*Direct observation and mechanism for enhanced electron emission sites in Pt ion implanted/post-annealed ultra nanocrystalline diamond films*”, The 62nd JSAP Spring Meeting, 11–14 March 2015, Tokai University, Kanagawa, Japan (*Oral presentation*).
 34. A. Saravanan, B. R Huang, K. J. Sankaran, N. H. Tai, and I. N. Lin, “*Enhancement on the plasma illumination properties and high stability electron field emission behavior of hybrid diamond films on Au/Si substrates grown by bias-enhanced nucleation and growth process*”, 9th International Conference on New Diamond and Nano Carbons 2015, 24–28, May 2015, Shizuoka Granship, Japan (*Poster presentation*).
 35. K. Panda, E. Inami, K. J Sankaran, Y. Sugimoto, I. N. Lin, “*Energy Dissipation of Tunneling Electrons as a Tool to Directly Detect Electron Emission Sites in Doped Ultrananocrystalline Diamond Films*”, NIMS Conference 2015 Materials Innovation Driven by Advanced Characterization, 14–16 July 2015, Tsukuba International Conference Center, Epochal, Tsukuba, Japan (*Poster presentation*).
 36. K. J. Sankaran, D.-Q. Hoang, K. Srinivasu, S. Korneychuk, S. Turner, P. Pobedinskas, S. Drijkoningen, J. Verbeeck, J. D’Haen, K. C. Leou, I. N. Lin, K. Haenen, “*Electron Field Emission Enhancement of Hexagonal Boron Nitride (hBN)-Nanocrystalline Diamond (NCD) Heterostructures*”, International Conference on Diamond and Carbon Materials, 6–10 September, 2015, Bad Homburg, Germany (*Oral presentation*).
 37. I-Nan Lin, C. J. Yeh, S. C. Lin, A. Saravanan, B. R. Huang, K. J. Sankaran, D. Manoharan, K. C. Leou, “*Development of diamond-based nano-carbon composite materials for electron field emitters and microplasma applications*”, International Conference on Diamond and Carbon Materials, 6–10 September, 2015, Bad Homburg, Germany (*Invited talk*).
 38. Joji Kurian, Kamatchi Jothiramalingam Sankaran, Nyan-Hwa Tai, and I-Nan Lin, “*Selective area growth of highly resistive ultrananocrystalline diamond films using copper patterned silicon substrates*,” First National Conference on Advanced Nanomaterials- CAN 2015, 1 and 2, October, 2015 , Department of Physics, Nirmalagiri College, Kannur, Kerala, India (*Poster presentation*).
 39. D. -Q. Hoang, P. Pobedinskas, K. J. Sankaran, S. D. Janssens, S. Turner, A. Hardy, J. Verbeeck, M.K. Van Bael, J. D’Haen, and K. Haenen “*RF deposited hexagonal boron nitride material and its applications*,” Inter University Symposium, The Belgo-Vietnamese Rector’s Mission 2015, 19 October, 2015 , Het Pand, Ghent, Belgium (*Poster presentation*).
 40. K. J Sankaran, I. N. Lin and K. Haenen “*Nanocrystalline Diamond Decorated Graphene Nanoflakes: Growth, Structural and Plasma Illumination Properties*”, II International Conference on Recent Trends in Materials, 22 and 23 January 2016, Devanga Arts College, Aruppukottai, Tamilnadu, India (*Poster presentation*).

41. K. J. Sankaran, D.-Q. Hoang, K. Srinivasu, S. Korneychuk, S. Turner, P. Pobedinskas, S. Drijkoningen, J. Verbeeck, J. D'Haen, K. C. Leou, I. N. Lin and K. Haenen, "*Enhanced Field Electron Emission from Hexagonal Boron Nitride–Diamond Nanorod Heterostructures*", Hasselt Diamond Workshop 2015-SBDD XXI, 9–11 March 2016, Hasselt, Belgium (*Poster presentation*).
42. K. J. Sankaran, D.-Q. Hoang, K. Srinivasu, S. Korneychuk, S. Turner, P. Pobedinskas, S. Drijkoningen, J. Verbeeck, J. D'Haen, K. C. Leou, I. N. Lin and K. Haenen, "*Engineering the Interface Characteristics on the Enhancement of Field Electron Emission Properties of Hexagonal Boron Nitride Nanowalls*", Hasselt Diamond Workshop 2015-SBDD XXI, 9–11 March 2016, Hasselt, Belgium (*Poster presentation*).
43. D. Q. Hoang, K. J. Sankaran, S. Korneychuk, P. Pobedinskas, S. Drijkoningen, S. Turner, S. S. Nicley, J. Verbeeck, M. K. Van Bael, J. D'Haen and K. Haenen, "*Direct observation of hBN crystallinity changes at the interface of hBN nanowalls and nanocrystalline CVD diamond*", Hasselt Diamond Workshop 2015-SBDD XXI, 9–11 March 2016, Hasselt, Belgium (*Poster presentation*).
44. M. Ficek, K. J. Sankaran, J. Ryl, R. Bogdanowicz, I. N. Lin, K. Haenen and K. Darowicki "*Optical properties and molecular composition of nitrogen doped diamond thin films grown in microwave CH₄/H₂/N₂ plasma enhanced chemical vapor deposition*", Hasselt Diamond Workshop 2015-SBDD XXI, 9–11 March 2016, Hasselt, Belgium (*Poster presentation*).
45. K. J. Sankaran, D.-Q. Hoang, K. Srinivasu, S. Korneychuk, S. Turner, P. Pobedinskas, S. Drijkoningen, J. Verbeeck, J. D'Haen, K. C. Leou, I. N. Lin and K. Haenen, "*Understanding Interface Characteristics of Hexagonal Boron Nitride-Diamond Heterostructures paves way for High Performance Opto-electronic Device Applications*", 2016 E-MRS Spring meeting, 2–6 May 2016, Lille, France (*Oral presentation*).
46. K. J. Sankaran, D.-Q. Hoang, K. Srinivasu, S. Korneychuk, S. Turner, P. Pobedinskas, S. Drijkoningen, J. Verbeeck, J. D'Haen, K. C. Leou, I. N. Lin and K. Haenen, "*High Performance Field Emission Electron Sources from Hexagonal Boron Nitride-Diamond Heterostructures*", 2016 E-MRS Spring meeting, 2–6 May 2016, Lille, France (*Oral presentation*).
47. K. J. Sankaran, D.-Q. Hoang, K. Srinivasu, S. Turner, P. T. Joseph, P. Pobedinskas, S. Drijkoningen, J. Verbeeck, J. D'Haen, K. C. Leou, K. T. Leung, I. N. Lin and K. Haenen, "*Enhanced Electron Emission from Boron Nitride Nanowall-Nanocrystalline Diamond Heterostructures*", New Diamond and Nano Carbons 2016, 22–26 May 2016, Xian, China (*Invited Talk*).
48. D. Q. Hoang, S. Korneychuk, K. J. Sankaran, P. Pobedinskas, S. Drijkoningen, S. Turner, M. K. Van Bael, J. Verbeeck, S. S. Nicley, and K. Haenen, "*Direct nucleation of hexagonal boron nitride on diamond: Crystalline properties of hBN nanowalls*", International

- Conference on Diamond and Carbon Materials, 4–8 September, 2016, Montpellier, France (*Poster presentation*).
49. K. J. Sankaran, “*Development of diamond-based hybrid materials for electron field emitters and microplasma cathode application*”, Global Congress and Expo on Materials Science and Nanoscience, 24–26 October 2016, Dubai, UAE (*Invited Talk*).
 50. K. J. Sankaran, D. Q. Hoang, S. Korneychuk, S. Kunuku, P.T. Joseph, P. Pobedinskas, S. Drijkoningen, M. K. Van Bael, J. D’Haen, J. Verbeeck, K. C. Leou, K. T. Leung, I. N. Lin, K. Haenen, “*Boron nitride nanowall– nanocrystalline diamond heterostructures – Interfacial and electron emission properties*”, 2016 MRS Fall Meeting, November 27–December 2, 2016, Hynes Convention Center & Sheraton Boston Hotel, Boston, MA, USA (*Oral presentation*).
 51. K. J. Sankaran, M. Ficek, C. J. Yeh, K. Srinivasu, R. Bogdanowicz, K. C. Leou, I. N. Lin and K. Haenen, “*Structural and electrical properties of boron doped diamond nanowalls*”, Hasselt Diamond Workshop-SBDD XXII, 8–10 March 2017, Hasselt, Belgium (*Poster presentation*).
 52. K. J. Sankaran, K. Srinivasu, C. J. Yeh, P. Pobedinskas, M. Schreck, K. C. Leou, I. N. Lin and K. Haenen, “*Field electron emission enhancement of nanocrystalline diamond films due to Li ion implantation and annealing processes*”, Hasselt Diamond Workshop-SBDD XXII, 8–10 March 2017, Hasselt, Belgium (*Oral presentation*).
 53. K. J. Sankaran, R. Ramaneti, S. Korneychuk, C. J. Yeh, G. Degutis, K. C. Leou, J. Verbeeck, M. K. Van Bael, I. N. Lin and K. Haenen, “*Vertically aligned patterned diamond-graphite hybrid nanorod arrays with superior field electron emission properties*”, 20 and 21 April 2017, 2nd Area Selective Deposition Workshop, Eindhoven, The Netherlands (*Poster presentation*).
 54. K. J. Sankaran, R. Ramaneti, S. Korneychuk, C. J. Yeh, G. Degutis, K. C. Leou, J. Verbeeck, M. K. Van Bael, I. N. Lin and K. Haenen, “*Vertically aligned patterned diamond-graphite hybrid nanorod arrays with superior field electron emission properties*”, New Diamond and Nano Carbons, 28 May–1 June 2017, Cairns, Australia (*Poster presentation*).
 55. K. J. Sankaran, “*Nanodiamond based hybrid materials for field electron emission applications*”, 22 June 2017, Gdansk University of Technology, Gdansk, Poland (*Guest Lecture*).
 56. K. J. Sankaran, “*Nanodiamond based hybrid materials for field electron emission applications*”, Smart Engineering of New Materials, 26–30 June 2017, Lodz, Poland (*Invited Talk*).
 57. K. J. Sankaran, S. Korneychuk, R. Ramaneti, S. Drijkoningen, K. Srinivasu, P. Pobedinskas, J. Verbeeck, M. K. Van Bael, I. N. Lin and K. Haenen, “*Vertically Aligned Diamond-Graphite Hybrid Nanorods for Thermionic and Field Electron Emission*

- Applications*”, International Conference on Diamond and Carbon Materials 3–7 September 2017, Gothenburg, Sweden (Oral presentation).
58. K. J. Sankaran, S. Korneychuk, S. Deshmukh, K. Srinivasu, S. Drijkoningen, P. Pobedinskas, G. Bhattacharya, J. Verbeeck, M. K. Van Bael, S. S. Roy, I. N. Lin and K. Haenen, “*Fabrication, Microstructure and Advanced Electron Emission Applications of Vertically Aligned Nitrogen-doped Nanocrystalline Diamond Nanorods*”, MRS Fall Meeting and Exhibit 26 November–1 December 2017, Boston, Massachusetts, USA (Oral presentation).
 59. K. J. Sankaran, M. Ficek, C. J. Yeh, K. Srinivasu, K. Panda, J. Y. Park, R. Bogdanowicz, K. C. Leou, I. N. Lin and K. Haenen, “*Self-organized Multilayered Graphene-Boron Doped Diamond Hybrid Nanowalls for High Performance Field Electron Emission Devices*”, MRS Fall Meeting and Exhibit 26 November–1 December 2017, Boston, Massachusetts, USA (Oral presentation).
 60. K. J. Sankaran, K. Srinivasu, C. J. Yeh, P. Pobedinskas, M. Schreck, I. N. Lin and K. Haenen, “*Field electron emission enhancement of nanocrystalline diamond films by lithium ion implantation and annealing*”, MRS Fall Meeting and Exhibit 26 November-1 December 2017, Boston, Massachusetts, USA (Oral presentation).
 61. Rajesh Ramaneti, Svetlana Korneychuk, Yan Zhou, Giedrius Degutis, K J Sankaran, Sien Drijkoningen, Paulius Pobedinskas, Joff Derluyn, Johan Verbeeck, Martin Kuball, Marlies van Bael, Ken Haenen, “*Diamond integration onto CMOS technology – from chemistry and interfacing to selective area growth and device applications*”, LGBT STEMINAR 2018, 12th January 2018, National STEM Learning Centre, University of York, York, UK.
 62. S. Deshmukh, K. J. Sankaran, D. Banerjee, K. Haenen and S. S. Roy, “*Probing of Enhanced Electron Emission Sites in N Doped Diamond Nanorods*”, International Conference on Current Trends in Materials Science and Engineering, 19 and 20 January 2018, S. N. Bose National Center for Basic Sciences, Kolkata, India (Best Oral Presentation Award).
 63. K. J. Sankaran, M. Ficek, C. J. Yeh, K. Srinivasu, K. Panda, J. Y. Park, R. Bogdanowicz, K. C. Leou, I. N. Lin and K. Haenen, “*High performance electron emission from cactus-like diamond nanostructures*”, Hasselt Diamond Workshop-SBDD XXIII, 7–9 March 2018, Hasselt, Belgium (Poster presentation).
 64. Daria Majchrowicz, Monika Kosowska, Kamatchi J. Sankaran, Przemysław Struk, Michał Wąsowicz, Michał Sobaszek, Ken Haenen, Małgorzata Jędrzejewska-Szczerska “*Nitrogen-doped diamond film for optical investigation of hemoglobin concentration*”, Hasselt Diamond Workshop-SBDD XXIII, 7-9 March 2018, Hasselt, Belgium (Poster presentation).
 65. Rajesh Ramaneti, K. J. Sankaran, Giedrius Degutis, Yan Zhou, Svetlana Korneychuk, Paulius Pobedinskas, Joff Derluyn, Johan Verbeeck, K. C. Leou, I. N. Lin, Martin Kuball,

- Ken Haenen, “Diamond in ‘Beyond CMOS’ technologies: From Surface Chemistry, Thermal Interface Studies to Chip-based Raman Spectroscopy and Micro/nano Patterned Field Emission Devices”, Hasselt Diamond Workshop-SBDD XXIII, 7–9 March 2018, Hasselt, Belgium (Poster presentation).
66. S. Deshmukh, K. J. Sankaran, S. Korneychuk, J. Verbeeck, K. Haenen, S. S. Roy, “Nanomolar level detection of Cd^{2+} and Pb^{2+} ions using N-doped diamond nanostructures”, Hasselt Diamond Workshop-SBDD XXIII, 7–9 March 2018, Hasselt, Belgium (Oral presentation).
67. K. J. Sankaran, K. Panda, B. Sundaravel, I. N. Lin, K. Haenen, “Local probing of the enhanced field electron emission of gold-diamond nanohybrids”, 12th International New Diamond and Nano Carbons Conference (NDNC 2018), May 20-24, 2018, Flagstaff, Arizona (Oral presentation).
68. Sankaran Kamatchi Jothiramalingam, Mateusz Ficek, Chien-Jui Yeh, Robert Bogdanowicz, Key-Chyang Leou, I-Nan Lin, Ken Haenen, “High Performance electron emission devices from self-organized multilayer graphene-diamond hybrid nanospines”, XXVII International Materials Research Congress 2018, August 19–24, 2018, Cancun, Mexico (Oral presentation).
69. Sankaran Kamatchi Jothiramalingam, Chien-Jui Yeh, Ping-Yen Hsieh, Paulius Pobedinskas, Key-Chyang Leou, Marlies K. Van Bael, Nyan-Hwa Tai, I-Nan Lin, Ken Haenen, “Tailoring the microstructure towards conductive nanocrystalline diamond films for enhanced field electron emission characteristics”, XXVII International Materials Research Congress 2018, August 19–24, 2018, Cancun, Mexico (Oral presentation).
70. Sankaran Kamatchi Jothiramalingam, Kalpataru Panda, Balakrishnan Sundaravel, I-Nan Lin, Ken Haenen, “Nanoscale investigation of enhanced field electron emission for gold-diamond nanohybrids”, XXVII International Materials Research Congress 2018, August 19–24, 2018, Cancun, Mexico (Oral presentation).
71. K. J. Sankaran, K. Haenen, “Nitrogen Incorporated (Ultra)Nanocrystalline Diamond Films for Field Electron Emission Applications”, 2nd edition of International Conference on Recent Trends in Materials Science and Technology-ICMST 2018, October 10–13, 2018, Thiruvananthapuram, India (*Invited talk*).
72. K. J. Sankaran, “Ultrananocrystalline Diamond Hybrids For Electron Emission Applications”, 4 October 2018, Shiv Nadar University, India (*Guest Lecture*).

EXECUTIVE SUMMARY

- Thin Films deposition using: Microwave Plasma Enhanced Chemical Vapor Deposition (MPECVD) IPLAS and ASTeX systems, Linear Antenna Microwave Plasma CVD system for Low Temperature Grown Diamond Films,

- RF Sputtering.
- Lithography (UV).
- Electron Field Emission and Thermionic Electron Emission Measurements.
- Microplasma Illuminations Measurements.
- Reactive Ion Etching.
- Familiar with polishing, and ion milling techniques.

HANDS-ON EXPERIENCE

- Transmission Electron Microscopy (JEOL 2100).
- Field Emission Scanning Electron Microscopy (JEOL 6500).
- Atomic Force Microscopy.
- Raman Spectroscopy.
- X-ray Diffraction.
- Fourier transform infrared spectroscopy.
- Electrochemical (AUTOLAB) measurements.
- Hall and Four-point probe resistivity measurements.

EXTRA CURRICULAR ACTIVITIES

- * Vice-President of Foreign Students Association (FSA), National Tsing Hua University, Taiwan (2010–2011).
- * Acting drama, writing poems, singing songs.

PERSONAL DETAILS

Gender	Male
Date of Birth	December 1, 1984
Nationality	India
Marital status	Married
Linguistic Proficiency	Tamil, English, Hindi, Kannada, Mandarin Chinese.

REFEREES

1. Prof. Ken Haenen,
Head, Wide bandgap Materials,
Institute for Materials Research,
Hasselt University,
Campus Diepenbeek, Wetenschapspark 1
Diepenbeek 3590, Belgium.

Email: ken.haenen@uhasselt.be

Ph: +32-11-26 88 75

2. Prof. Nyan-Hwa Tai (Ph.D Advisor)
Department of Materials Science and Engineering,
National Tsing Hua University, Hsinchu, Taiwan.
Email: nhtai@mse.nthu.edu.tw
Ph: +886-3-5715131 # 42568
Fax: +886-3-5722366

3. Prof. I-Nan Lin (Ph.D Co-Advisor)
Department of Physics,
Tamkang University, Tamsui, Taiwan.
Email: inanlin@mail.tku.edu.tw
Ph: +886-2-26268907
Fax: +886-2-26209917

4. Dr. B. Sundaravel,
Scientist,
Materials Science Group,
Indira Gandhi Center for Atomic Research,
Kalpakkam,
Tamilnadu, India.
Email: sundaravelb@gmail.com
Ph: +91 44 27480500